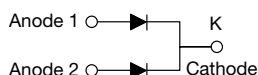
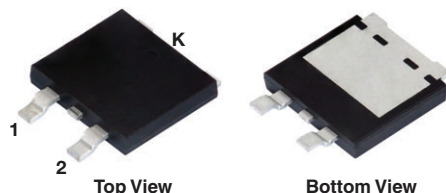


# Ultrafast Rectifier, 2 x 6 A FRED Pt®

## eSMP® Series SMPD (TO-263AC)



## FEATURES

- Ultrafast recovery time, reduced  $Q_{rr}$ , and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM, snubber operation
- Low forward voltage drop
- Low leakage current
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see [www.vishay.com/doc?99912](http://www.vishay.com/doc?99912)



## LINKS TO ADDITIONAL RESOURCES



| PRIMARY CHARACTERISTICS |                 |
|-------------------------|-----------------|
| $I_{F(AV)}$             | 2 x 6 A         |
| $V_R$                   | 600 V           |
| $V_F$ at $I_F$          | 0.89 V          |
| $t_{rr}$                | 45 ns           |
| $T_J$ max.              | 175 °C          |
| Package                 | SMPD (TO-263AC) |
| Circuit configuration   | Common cathode  |

## DESCRIPTION / APPLICATIONS

State of the art ultrafast recovery rectifiers specifically designed with optimized performance of forward voltage drop and ultrafast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness, and reliability characteristics.

These devices are intended for use in PFC, boost, in the AC/DC section of SMPS, freewheeling and clamp diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce power dissipation in the switching element and snubbers

## MECHANICAL DATA

**Case:** SMPD (TO-263AC)

Molding compound meets UL 94 V-0 flammability rating  
Halogen-free, RoHS-compliant

**Terminals:** matte tin plated leads, solderable per J-STD-002

| ABSOLUTE MAXIMUM RATINGS          |             |                                          |        |       |
|-----------------------------------|-------------|------------------------------------------|--------|-------|
| PARAMETER                         | SYMBOL      | TEST CONDITIONS                          | VALUES | UNITS |
| Peak repetitive reverse voltage   | $V_{RRM}$   |                                          | 600    | V     |
| Average rectified forward current | $I_{F(AV)}$ | $T_{solder\ pad} = 156\ ^\circ C$        | 12     | A     |
|                                   |             |                                          | 6      |       |
| Non-repetitive peak surge current | $I_{FSM}$   | $T_J = 25\ ^\circ C$ , 6 ms square pulse | 200    |       |
|                                   |             |                                          | 105    |       |

| ELECTRICAL SPECIFICATIONS ( $T_J = 25\ ^\circ C$ unless otherwise specified) |               |                                         |      |      |      |         |
|------------------------------------------------------------------------------|---------------|-----------------------------------------|------|------|------|---------|
| PARAMETER                                                                    | SYMBOL        | TEST CONDITIONS                         | MIN. | TYP. | MAX. | UNITS   |
| Breakdown voltage, blocking voltage                                          | $V_{BR}, V_R$ | $I_R = 100\ \mu A$                      | 600  | -    | -    | V       |
| Forward voltage, per diode                                                   | $V_F$         | $I_F = 6\ A$                            | -    | 1.05 | 1.3  |         |
|                                                                              |               | $I_F = 6\ A, T_J = 150\ ^\circ C$       | -    | 0.89 | 1.1  |         |
| Reverse leakage current, per diode                                           | $I_R$         | $V_R = V_R\ rated$                      | -    | -    | 5    | $\mu A$ |
|                                                                              |               | $T_J = 150\ ^\circ C, V_R = V_R\ rated$ | -    | 20   | 150  |         |
| Junction capacitance, per diode                                              | $C_T$         | $V_R = 600\ V$                          | -    | 8    | -    | pF      |

**DYNAMIC RECOVERY CHARACTERISTICS** ( $T_J = 25\text{ }^{\circ}\text{C}$  unless otherwise specified)

| PARAMETER               | SYMBOL    | TEST CONDITIONS                                                                | MIN. | TYP. | MAX. | UNITS |
|-------------------------|-----------|--------------------------------------------------------------------------------|------|------|------|-------|
| Reverse recovery time   | $t_{rr}$  | $I_F = 1\text{ A}$ , $di_F/dt = 50\text{ A}/\mu\text{s}$ , $V_R = 30\text{ V}$ | -    | 45   | -    | ns    |
|                         |           | $I_F = 0.5\text{ A}$ , $I_R = 1\text{ A}$ , $I_{rr} = 0.25\text{ A}$           | -    | -    | 60   |       |
|                         |           | $T_J = 25\text{ }^{\circ}\text{C}$                                             | -    | 65   | -    |       |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                            | -    | 90   | -    |       |
| Peak recovery current   | $I_{RRM}$ | $T_J = 25\text{ }^{\circ}\text{C}$                                             | -    | 10   | -    | A     |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                            | -    | 15   | -    |       |
| Reverse recovery charge | $Q_{rr}$  | $T_J = 25\text{ }^{\circ}\text{C}$                                             | -    | 350  | -    | nC    |
|                         |           | $T_J = 125\text{ }^{\circ}\text{C}$                                            | -    | 680  | -    |       |

**THERMAL - MECHANICAL SPECIFICATIONS**

| PARAMETER                                       | SYMBOL            | TEST CONDITIONS            | MIN.    | TYP. | MAX. | UNITS                       |
|-------------------------------------------------|-------------------|----------------------------|---------|------|------|-----------------------------|
| Maximum junction and storage temperature range  | $T_J$ , $T_{Stg}$ |                            | -55     | -    | +175 | $^{\circ}\text{C}$          |
| Thermal resistance, per diode junction to mount | $R_{thJM}$        |                            | -       | 1.8  | 2.5  | $^{\circ}\text{C}/\text{W}$ |
| Approximate weight                              |                   |                            | 0.55    |      |      | g                           |
|                                                 |                   |                            | 0.02    |      |      | oz.                         |
| Marking device                                  |                   | Case style SMPD (TO-263AC) | 12CDU06 |      |      |                             |

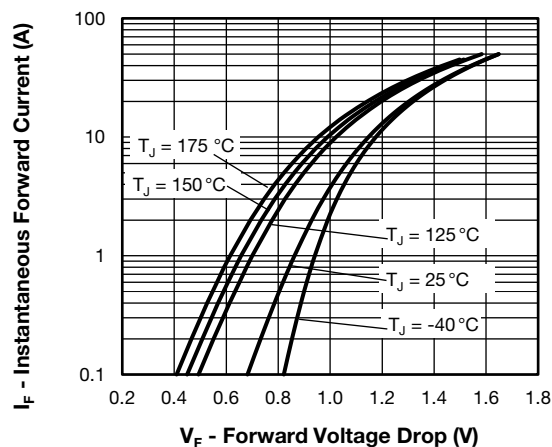


Fig. 1 - Typical Forward Voltage Drop Characteristics

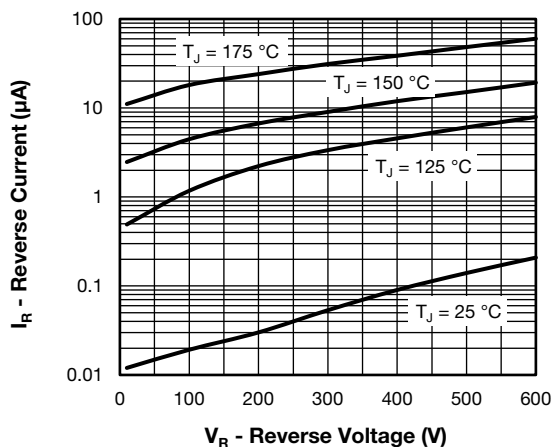


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

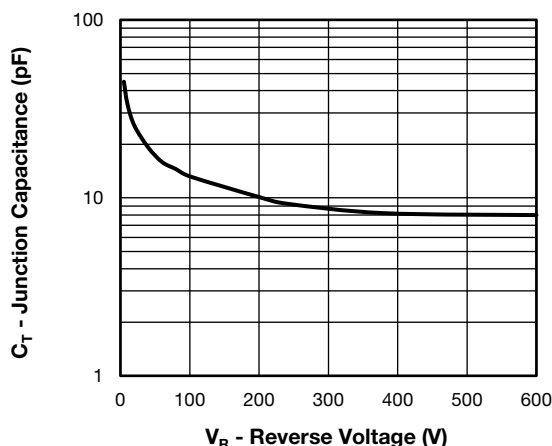


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

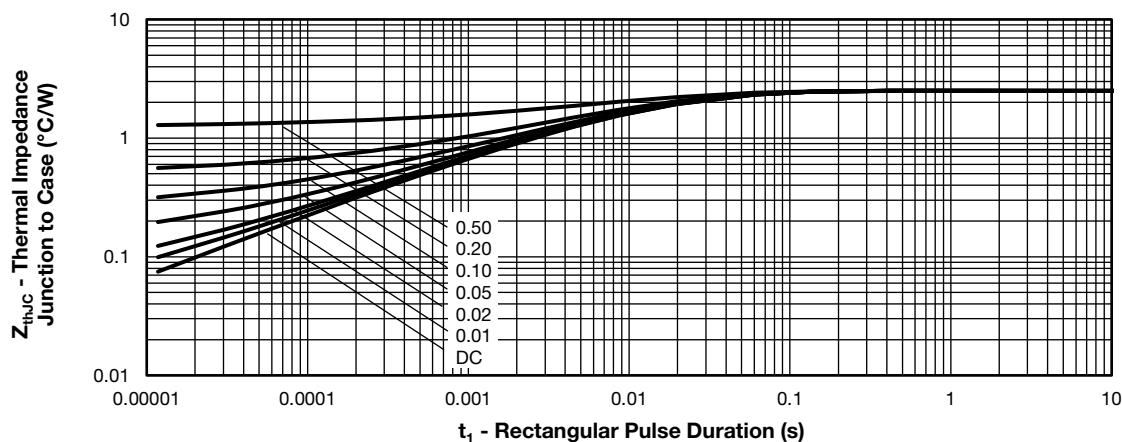
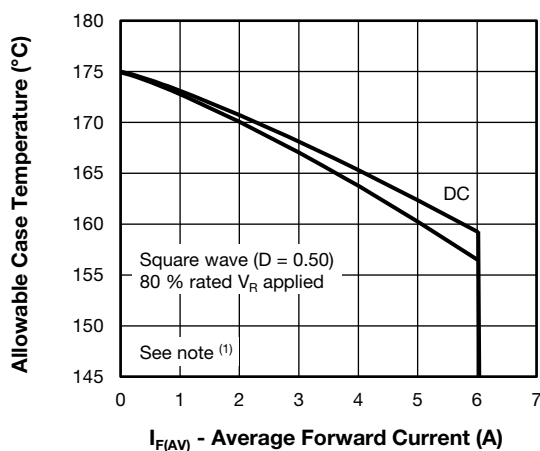

Fig. 4 - Maximum Thermal Impedance  $Z_{thJC}$  Characteristics


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

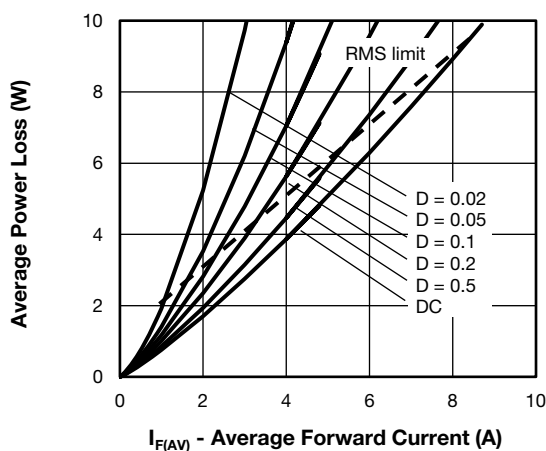


Fig. 6 - Forward Power Loss Characteristics

#### Note

- (1) Formula used:  $T_C = T_J - (P_d + P_{dREV}) \times R_{thJC}$ ;  
 $P_d$  = forward power loss =  $I_{F(AV)} \times V_{FM}$  at  $(I_{F(AV)}/D)$  (see fig. 5);  
 $P_{dREV}$  = inverse power loss =  $V_{R1} \times I_R (1 - D)$ ;  $I_R$  at  $V_{R1}$  = rated  $V_R$

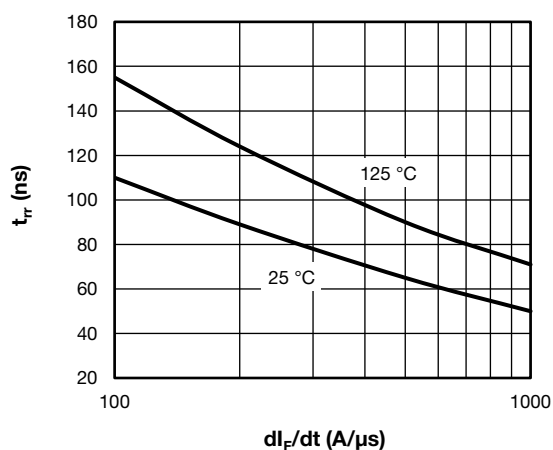
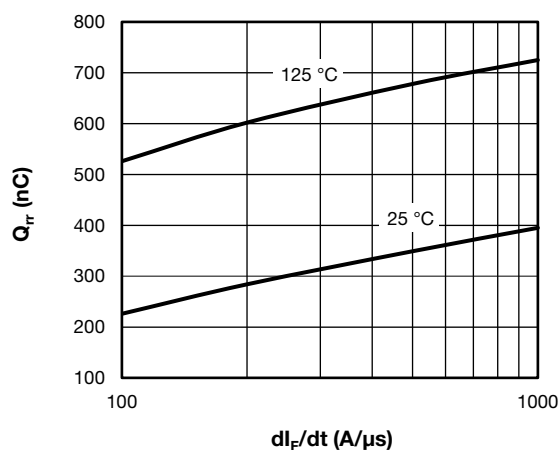
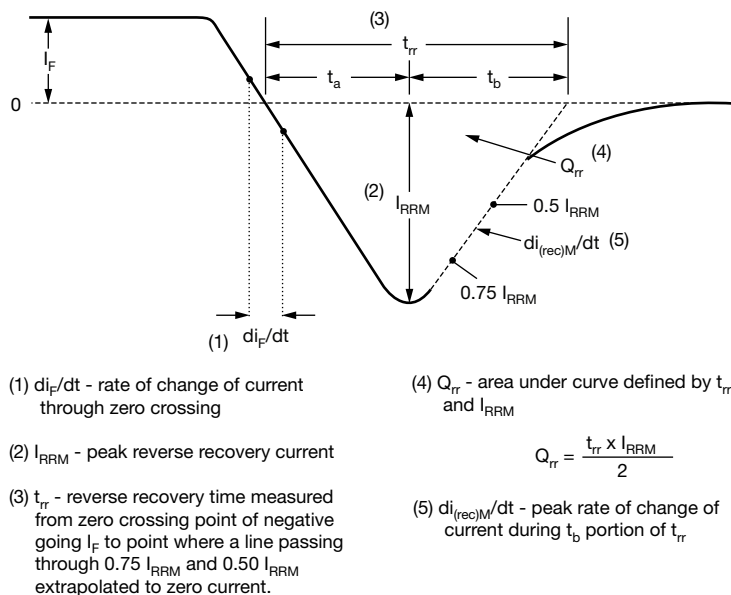

Fig. 7 - Typical Reverse Recovery Time vs.  $di_F/dt$ 

Fig. 8 - Typical Stored Charge vs.  $di_F/dt$ 


Fig. 9 - Reverse Recovery Waveform and Definitions



## ORDERING INFORMATION TABLE

|             |     |    |   |   |   |    |   |    |
|-------------|-----|----|---|---|---|----|---|----|
| Device code | VS- | 12 | C | D | U | 06 | H | M3 |
|             | 1   | 2  | 3 | 4 | 5 | 6  | 7 | 8  |

- 1** - Vishay Semiconductors product
- 2** - Current rating (12 A)
- 3** - Circuit configuration:  
C = common cathode
- 4** - D = SMPD package
- 5** - Process type,  
U = ultrafast recovery
- 6** - Voltage code (06 = 600 V)
- 7** - H = AEC-Q101 qualified
- 8** - M3 = halogen-free, RoHS-compliant, and terminations lead (Pb)-free

### ORDERING INFORMATION (Example)

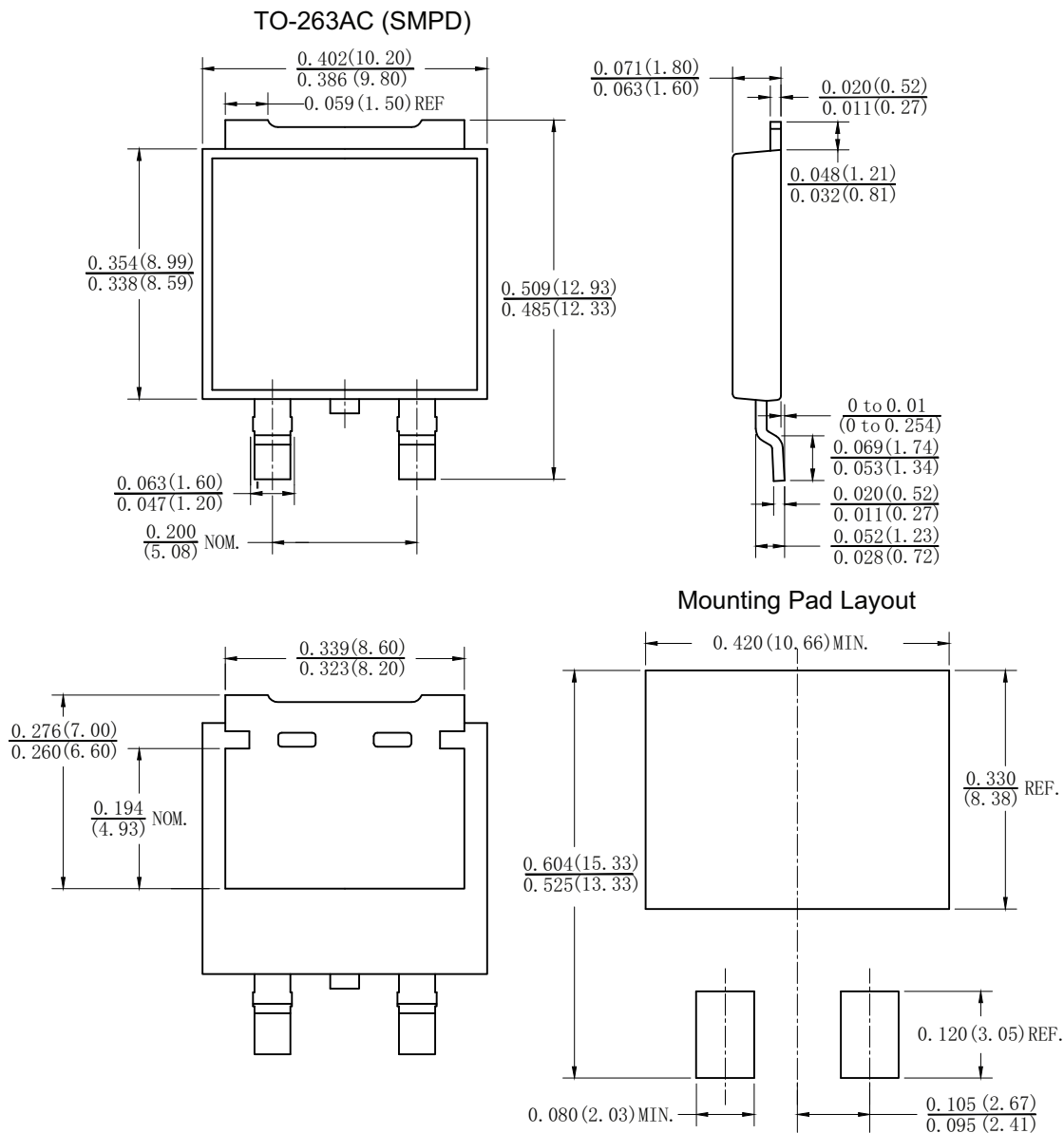
| PREFERRED P/N   | QUANTITY PER REEL | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION              |
|-----------------|-------------------|------------------------|------------------------------------|
| VS-12CDU06HM3/I | 2000              | 2000                   | 13" diameter plastic tape and reel |

### LINKS TO RELATED DOCUMENTS

|                          |                                                                        |
|--------------------------|------------------------------------------------------------------------|
| Dimensions               | <a href="http://www.vishay.com/doc?95604">www.vishay.com/doc?95604</a> |
| Part marking information | <a href="http://www.vishay.com/doc?95566">www.vishay.com/doc?95566</a> |
| Packaging information    | <a href="http://www.vishay.com/doc?88869">www.vishay.com/doc?88869</a> |

### TO-263AC (SMPD)

**DIMENSIONS** in inches (millimeters)





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